

Surface Mount Automotive Transient Voltage Suppressors

High Temperature Stability and High Reliability Conditions

Patented*

* Patent #'s:
4,980,315
5,166,769
5,278,095


DO-218AB
FEATURES

- Patented PAR[®] construction
- Available in uni-directional polarity only
- Low leakage current
- Low forward voltage drop
- High surge capability
- Meets ISO7637-2 surge spec (varied by test condition)
- Meets MSL level 1, per J-STD-020C, LF max peak of 245 °C
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC


PRIMARY CHARACTERISTICS

V_{WM}	10 V to 43 V
P_{PPM} (10 x 1000 μ s)	6600 W
P_{PPM} (10 x 10000 μ s)	5200 W
P_D	8 W
I_{FSM}	700 A
T_J max.	175 °C

TYPICAL APPLICATIONS

Use in sensitive electronics protection against voltage transients induced by inductive load switching and lighting, especially for automotive load dump protection application.

MECHANICAL DATA

Case: DO-218AB

Epoxy meets UL 94V-0 flammability rating

Terminals: Matte tin plated leads, solderable per J-STD-002B and JESD22-B102D

HE3 suffix for high reliability grade (AEC Q101 qualified)

Polarity: Heatsink is anode

MAXIMUM RATINGS ($T_C = 25$ °C unless otherwise noted)

PARAMETER	SYMBOL	VALUE	UNIT
Peak pulse power dissipation with 10/1000 μ s waveform with 10/10000 μ s waveform	P_{PPM}	6600 5200	W
Power dissipation on infinite heatsink at $T_C = 25$ °C (Fig. 1)	P_D	8.0	W
Peak pulse current with 10/1000 μ s waveform ⁽¹⁾	I_{PPM}	See next table	A
Peak forward surge current 8.3 ms single half sine-wave	I_{FSM}	700	A
Operating junction and storage temperature range	T_J, T_{STG}	- 55 to + 175	°C

Note:

(1) Non-repetitive current pulse derated above $T_A = 25$ °C

SM8S10 thru SM8S43A

Vishay General Semiconductor



ELECTRICAL CHARACTERISTICS ($T_C = 25\text{ }^\circ\text{C}$ unless otherwise noted)								
DEVICE TYPE	BREAKDOWN VOLTAGE V_{BR} (V)		TEST CURRENT I_T (mA)	STAND-OFF VOLTAGE V_{WM} (V)	MAXIMUM REVERSE LEAKAGE AT V_{WM} I_D (μA)	MAXIMUM REVERSE LEAKAGE AT V_{WM} $T_J = 175\text{ }^\circ\text{C}$ I_D (μA)	MAX. PEAK PULSE CURRENT AT 10/1000 μs WAVEFORM (A)	MAXIMUM CLAMPING VOLTAGE AT I_{PPM} V_C (V)
	MIN	MAX						
SM8S10	11.1	13.6	5.0	10.0	15	250	351	18.8
SM8S10A	11.1	12.3	5.0	10.0	15	250	388	17.0
SM8S11	12.2	14.9	5.0	11.0	10	150	328	20.1
SM8S11A	12.2	13.5	5.0	11.0	10	150	363	18.2
SM8S12	13.3	16.3	5.0	12.0	10	150	300	22.0
SM8S12A	13.3	14.7	5.0	12.0	10	150	332	19.9
SM8S13	14.4	17.6	5.0	13.0	10	150	277	23.8
SM8S13A	14.4	15.9	5.0	13.0	10	150	307	21.5
SM8S14	15.6	19.1	5.0	14.0	10	150	256	25.8
SM8S14A	15.6	17.2	5.0	14.0	10	150	284	23.2
SM8S15	16.7	20.4	5.0	15.0	10	150	245	26.9
SM8S15A	16.7	18.5	5.0	15.0	10	150	270	24.4
SM8S16	17.8	21.8	5.0	16.0	10	150	229	28.8
SM8S16A	17.8	19.7	5.0	16.0	10	150	254	26.0
SM8S17	18.9	23.1	5.0	17.0	10	150	216	30.5
SM8S17A	18.9	20.9	5.0	17.0	10	150	239	27.6
SM8S18	20.0	24.4	5.0	18.0	10	150	205	32.2
SM8S18A	20.0	22.1	5.0	18.0	10	150	226	29.2
SM8S20	22.2	27.1	5.0	20.0	10	150	184	35.8
SM8S20A	22.2	24.5	5.0	20.0	10	150	204	32.4
SM8S22	24.4	29.8	5.0	22.0	10	150	168	39.4
SM8S22A	24.4	26.9	5.0	22.0	10	150	186	35.5
SM8S24	26.7	32.6	5.0	24.0	10	150	153	43.0
SM8S24A	26.7	29.5	5.0	24.0	10	150	170	38.9
SM8S26	28.9	35.3	5.0	26.0	10	150	142	46.6
SM8S26A	28.9	31.9	5.0	26.0	10	150	157	42.1
SM8S28	31.1	38.0	5.0	28.0	10	150	132	50.1
SM8S28A	31.1	34.4	5.0	28.0	10	150	145	45.4
SM8S30	33.3	40.7	5.0	30.0	10	150	123	53.5
SM8S30A	33.3	36.8	5.0	30.0	10	150	136	48.4
SM8S33	36.7	44.9	5.0	33.0	10	150	112	59.0
SM8S33A	36.7	40.6	5.0	33.0	10	150	124	53.3
SM8S36	40.0	48.9	5.0	36.0	10	150	103	64.3
SM8S36A	40.0	44.2	5.0	36.0	10	150	114	58.1
SM8S40	44.4	54.3	5.0	40	10	150	92.4	71.4
SM8S40A	44.4	49.1	5.0	40	10	150	102	64.5
SM8S43	47.8	58.4	5.0	43	10	150	86	76.7
SM8S43A	47.8	52.8	5.0	43	10	150	95.1	69.4

Note:

For all types maximum $V_F = 1.8\text{ V}$ at $I_F = 100\text{ A}$ measured on 8.3 ms single half sine-wave or equivalent square wave, duty cycle = 4 pulses per minute maximum

THERMAL CHARACTERISTICS ($T_C = 25\text{ }^\circ\text{C}$ unless otherwise noted)			
PARAMETER	SYMBOL	VALUE	UNIT
Typical thermal resistance, junction to case	$R_{\theta JC}$	0.90	$^\circ\text{C/W}$



ORDERING INFORMATION (Example)				
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE
SM8S10AHE3/2D ⁽¹⁾	2.605	2D	750	13" diameter paper tape and reel, anode towards the sprocket hole

Note:

(1) Automotive grade AEC Q101 qualified

RATINGS AND CHARACTERISTICS CURVES

(T_A = 25 °C unless otherwise noted)

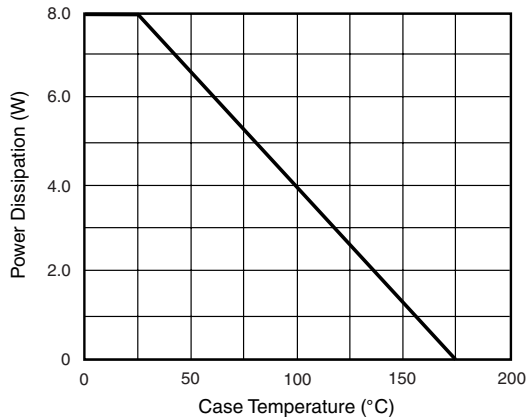


Figure 1. Power Derating Curve

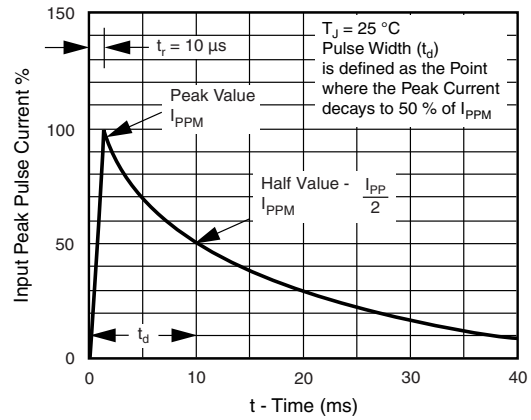


Figure 3. Pulse Waveform

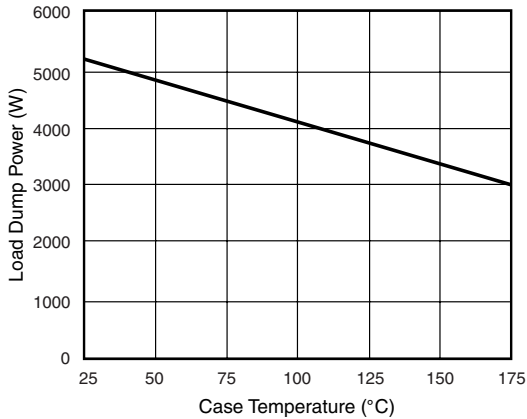


Figure 2. Load Dump Power Characteristics (10 ms Exponential Waveform)

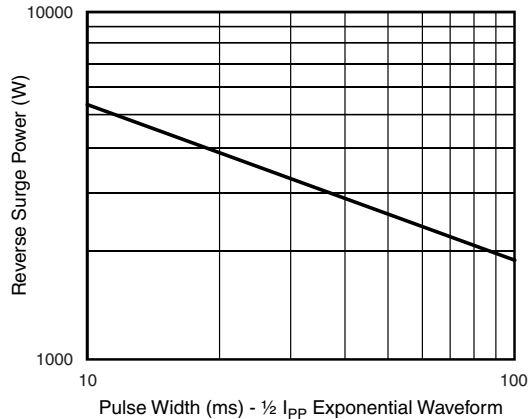


Figure 4. Reverse Power Capability

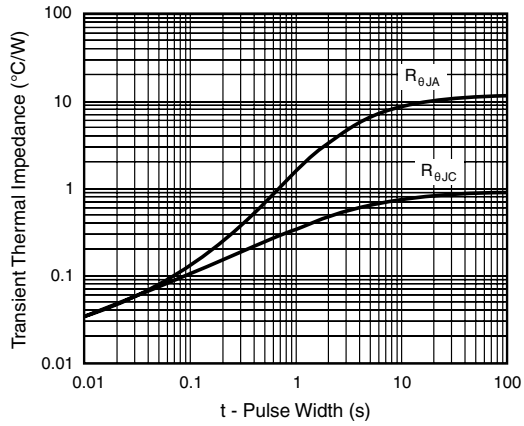
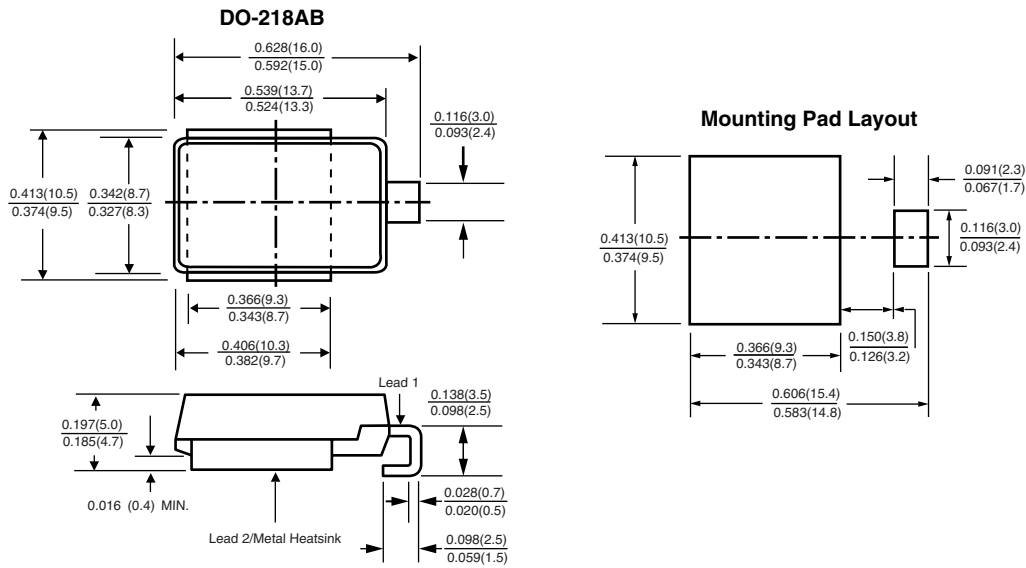


Figure 5. Typical Transient Thermal Impedance

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)





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